

RELIABILITY REPORT

FOR

MAX11633EEG+

PLASTIC ENCAPSULATED DEVICES

November 23, 2010

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by
Sokhom Chum
Quality Assurance
Reliability Engineer



Conclusion

The MAX11633EEG+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim"s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim"s quality and reliability standards.

Table of Contents

IDevice Description	VQuality Assurance Information		
IIManufacturing Information	VIReliability Evaluation		
IIIPackaging Information	IVDie Information		
Attachments			

I. Device Description

A. General

The MAX11626-MAX11629/MAX11632/MAX11633 are serial 12-bit analog-to-digital converters (ADCs) with an internal reference. These devices feature on-chip FIFO, scan mode, internal clock mode, internal averaging, and AutoShutdown(tm). The maximum sampling rate is 300ksps using an external clock. The MAX11632/MAX11633 have 16 input channels, the MAX11628/MAX11629 have 8 input channels, and the MAX11626/MAX11627 have 4 input channels. These eight devices operate from either a +3V supply or a +5V supply, and contain a 10MHz SPI(tm)/QSPI(tm)/MICROWIRE(tm)-compatible serial port. The MAX11626-MAX11629 are available in 16-pin QSOP packages. The MAX11632/MAX11633 are available in 24-pin QSOP packages. All eight devices are specified over the extended -40°C to +85°C temperature range.



II. Manufacturing Information

A. Description/Function: 12-Bit, 300ksps ADCs with FIFO and Internal Reference

B. Process: C6Y
C. Number of Device Transistors: 31874
D. Fabrication Location: Japan
E. Assembly Location: Thailand
F. Date of Initial Production: June 23, 2010

III. Packaging Information

A. Package Type: 24-pin QSOP
B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin
D. Die Attach: Conductive
E. Bondwire: Au (0.8 mil dia.)
F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: #

H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per Level 1

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 105°C/W
K. Single Layer Theta Jc: 34°C/W
L. Multi Layer Theta Ja: 88°C/W
M. Multi Layer Theta Jc: 34°C/W

IV. Die Information

A. Dimensions: 90 X 130 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Al with Ti/TiN Barrier

D. Backside Metallization: None

E. Minimum Metal Width: 0.6 microns (as drawn)F. Minimum Metal Spacing: 0.6 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.
H. Isolation Dielectric: SiO₂
I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)

Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppmD. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (3) is calculated as follows:

$$_{\lambda}$$
 = $_{\frac{1}{\text{MTTF}}}$ = $_{\frac{1.83}{192 \times 4340 \times 48 \times 2}}$ (Chi square value for MTTF upper limit) (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$x = 22.9 \times 10^{-9}$$

 $x = 22.9 \text{ F.I.T. (60\% confidence level @ 25°C)}$

The following failure rate represents data collected from Maxim"s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the C6Y Process results in a FIT Rate of 0.90 @ 25C and 15.55 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot EF4ZAQ001B, DC 1001)

The AC88 die type has been found to have all pins able to withstand a HBM transient pulse +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA and overvoltage per JEDEC JESD78.



Table 1

Reliability Evaluation Test Results

MAX11633EEG+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS		
Static Life Test (Note 1)							
	Ta = 135°C	DC Parameters	48	0	EF4ZAQ001B, DC 1001		
	Biased						
	Time = 192 hrs.	& functionality					

Note 1: Life Test Data may represent plastic DIP qualification lots.